L Number	Hits	Search Text	DB	Time stamp
_	468	349/122	USPAT	2002/03/07 14:35
_	441	349/138	USPAT	2001/08/30 09:54
_				2001/08/30 09:56
-	429	349/113	USPAT	
-	839	(passivation or dielectric) and (liquid adj	USPAT	2002/03/07 14:40
		crystal) and (change\$ with reflect\$) and		
[thick\$		
-	56	(passivation or dielectric) and (change\$	USPAT	2001/08/30 10:44
		with reflect\$) and thick\$ and 349/113		
l _	19	(passivation or dielectric) and (change\$	USPAT	2001/08/30 11:05
		with reflect\$) and thick\$ and 349/138		
	18	(passivation or dielectric) and (change\$	USPAT	2001/08/30 11:15
	10		USFAI	2001/08/30 11:13
		with reflect\$) and thick\$ and 349/122		
-	503	349/122	USPAT	2002/03/07 14:37
-	483	349/138	USPAT	2002/03/07 14:38
-	490	349/149	USPAT	2002/03/07 14:39
-	939	349/42	USPAT	2002/03/07 14:39
l -	616		USPAT	2002/03/07 14:39
_	11044		USPAT	2002/03/07 14:41
_	11011	crystal)	001111	2002,03,0, 21.11
			HODAM	2002/02/02 02 41
i - '	289	· · ·	USPAT	2002/03/08 09:41
		(liquid adj crystal))		
-	214	· · · ·	USPAT	2002/03/07 14:43
		(liquid adj crystal))		
_	496	349/42 and ((passivation or dielectric) and	USPAT	2002/03/07 14:43
		(liquid adj crystal))		
_	369	349/43 and ((passivation or dielectric) and	USPAT	2002/03/07 14:43
	309	(liquid adj crystal))	OSFAI	2002/03/07 14:45
	1.0		110000	2002/02/07 14 45
-	149	((passivation or dielectric) and (liquid adj	USPAT	2002/03/07 14:45
		crystal)) and (periphe\$4 adj region)		
- '	369	' ' ' 	USPAT	2002/03/08 08:33
		adj crystal)) and (periphe\$4 adj circuit))		
		or (((passivation or dielectric) and (liquid		
		adj crystal)) and (periphe\$4 adj region))		
l _	217	349/113 and ((passivation or dielectric) and	USPAT	2002/03/07 17:45
	•••	(liquid adj crystal))	001111	2002,00,01
	220	349/113 and (passivation or dielectric)	USPAT	2002/03/07 16:30
-	[USPAT	2002/03/07 17:30
_	488			, ,
-	313		USPAT	2002/03/07 17:47
		silicon) and (liquid adj crystal))		
-	706		USPAT	2002/03/08 08:39
		silicon)and(liquid adj crystal)) and		
		((periphe\$4 adj circuit)or(periphe\$4 adj		
		region))	ļ	
<u>-</u>	359	((passivation or dielectric or	USPAT	2002/03/08 08:39
	1	silicon)and(liquid adj crystal)) and	001111	=====
		((periphe\$4 adj circuit)or(periphe\$4 adj		
!	224	region)) and panel	110000	2002/02/02 02 40
- !	204	((passivation or dielectric or	USPAT	2002/03/08 08:40
		silicon) and (liquid adj crystal)) and		
		((periphe\$4 adj circuit)or(periphe\$4 adj	1	
i l		region)) and panel and reflect\$6		
-	12	((passivation or dielectric) and (liquid adj	USPAT	2002/03/08 09:14
		crystal)) and (periphery adj circuit)		1
-	. 235		USPAT	2002/03/08 09:15
ļ	233	crystal)) and (periphe\$4 adj circuit)		
i _	179	349/138 and (passivation or dielectric or	USPAT	2002/03/08 09:43
_	1/9		USPAI	2002/03/08 09:43
		silicon) and (edge or periphery)		2000/00/00 27 05
			USPAT	2002/03/08 11:06
-	47	349/138 and (passivation or dielectric or	001111	
-	47	silicon) and (edge or periphery)and seal		
-	47	silicon) and (edge or periphery)and seal 349/43 and (passivation or dielectric or	USPAT	2002/03/08 10:05
-		silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal		
-		silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal		
-	41	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or	USPAT	2002/03/08 10:05 2002/03/08 10:51
- - -	41 65	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal	USPAT	2002/03/08 10:51
-	41	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or	USPAT	
-	41 65 22	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or silicon) and (edge or periphery) and seal	USPAT USPAT USPAT	2002/03/08 10:51 2002/03/08 11:06
-	41 65	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/122 and (passivation or dielectric or	USPAT	2002/03/08 10:51
- - -	41 65 22 46	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/122 and (passivation or dielectric or silicon) and (edge or periphery) and seal	USPAT USPAT USPAT	2002/03/08 10:51 2002/03/08 11:06 2002/03/08 11:07
- - -	41 65 22	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/122 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/149 and (passivation or dielectric or	USPAT USPAT USPAT	2002/03/08 10:51 2002/03/08 11:06
- - -	41 65 22 46	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/122 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/149 and (passivation or dielectric or silicon) and (edge or periphery) and seal	USPAT USPAT USPAT	2002/03/08 10:51 2002/03/08 11:06 2002/03/08 11:07
- - -	41 65 22 46	silicon) and (edge or periphery) and seal 349/43 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/42 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/113 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/122 and (passivation or dielectric or silicon) and (edge or periphery) and seal 349/149 and (passivation or dielectric or	USPAT USPAT USPAT	2002/03/08 10:51 2002/03/08 11:06 2002/03/08 11:07

- 1 6344888.pn. USPAT 2004/01/14 16:45